

**11.1-13** OPTICAL PROCESSING OF X-RAY TOPOGRAPHS. By V.V. Aristov, G.A. Bashkina, L.V. Dorozhkina, A.I. Erko, Institute of Solid State Physics, Academy of Sciences of the USSR, Chernogolovka, Moscow District, 142432, USSR.

The paper describes the results of the processing of X-ray topographs in the scheme of optical coherent filtering. For the images of Si perfect crystals obtained in the symmetrical Laue-case the resolution was improved by an order of magnitude and the sensitivity to the structure defects of the crystals was enhanced. Computer simulation of the process of filtering made it possible to relate the permissible sensitivity of the method to the size of the structure defect.

**11.1-15** SYNCHROTRON RADIATION TOPOGRAPHY OF CUBIC (100)Co-(8wt%)Fe BINARY ALLOY.

By J.D. Stephenson, Freie Un.Berlin and Fritz-Haber Inst. der Max Planck Gesellschaft, Dahlem, Berlin.

Polychromatic synchrotron radiation (DORIS, Hamburg) is used in Bragg reflection topography to observe magnetic stripe domain structure in the binary ferromagnetic alloy Co-(8wt%)Fe when subjected to [100]-compression and a variable [100]-magnetic field. Different domain structure is observed in simultaneous 511- and 822- reflections and possibly can be explained by primary extinction contrast.

Previous assumptions presumed that the optimum domain contrast was produced by interbranch scattering from Y-junctions formed between 90° and 180° Bloch walls, situated at depths corresponding to i) the first pendellösung minimum in the Laue transmission case and ii) the first pendellösung maximum for the Bragg back reflection case. Primary extinction contrast theory is shown to be capable of explaining the light grey-dark grey contrast sometimes observed between alternate stripe domains in X-ray topographs (Stephenson, phys. stat. sol. (a) 64, XXX, (1981) and to give an approximate depth of the Y-junctions below the surface of the crystal.

Calculations indicate that the depths of Y-junctions in the case of Co-(8wt%)Fe are within 0-6 μm for those producing dark grey contrast and within 10 to 12 μm for those producing light grey contrast.

Similar experiments on Fe-(8wt%)Si crystals indicated that the Y-junction depths were approximately 9 to 12 μm below the surface (Stephenson, Tuomi and Kelhä, phys. stat. sol. (a), 57, 191 (1980) which were of the same order of magnitude (5 μm) directly observed in iron single crystal whiskers by Chikaura et al, J. Phys. Soc. Japan, 35, 404 (1973).

**11.1-14** ON THE CHANNEL ORIGIN IN THE CRYSTALS.

By E. Scandale, Istituto di Mineralogia e Petrografia, Università di Bari, Italy and A. Zarka, Laboratoire de Mineralogie-Cristallographie, Université P. et M. Curie, Paris VI, France.

Although channels are often observed in crystals, their formation mechanism is not well understood. In the present work, several natural and synthetic crystals were studied by X-ray topography and in the optical microscope using polarized light. The results suggest no single explanation for the origin of channels, but some of these defects appear to have, in different crystals, dislocation-like features (i.e. configuration, topographic contrast). A good correlation was established between the optical contrast and the topographic contrast of the heavily strained region around these defects. Computer simulations of the diffraction contrast of dislocation bundles are actually in progress to match the optical and topographic observations.

**11.1-16** STUDY OF PERFECTION OF FLUX GROWN  $\alpha$ -Al<sub>2</sub>O<sub>3</sub> SINGLE CRYSTALS BY TRANSMISSION X-RAY DIFFRACTION TOPOGRAPHY. By Krishan Lal and Vijay Kumar, National Physical Laboratory, Hillside Road, New Delhi -110012, INDIA.

$\alpha$ -Al<sub>2</sub>O<sub>3</sub> crystals have been grown by a number of techniques like Vernueil method, Czochralski method, chemical vapour deposition (CVD) method and flux method. We had undertaken a comparative study of perfection of  $\alpha$ -Al<sub>2</sub>O<sub>3</sub> single crystals grown by different methods (Lal and Kumar, J. Electrochem. Soc. 125, 2079 (1978); Lal, Kumar and Verma, Indian J. Phys. 53A, 78 (1979)). In the present paper results of study of perfection of flux grown crystals are described. The specimen used in this investigation have their larger faces parallel to the basal plane (0001). Almost all the crystals investigated were free of grain boundaries and low angle boundaries. However, these gave fairly broad diffraction curves even though the peaks due to K $\alpha_1$  and K $\alpha_2$  characteristic radiation were resolved. It shows that the general degree of perfection of these crystals is good. As reported earlier, the Czochralski grown material has low angle boundaries. CVD grown crystals on the other hand showed much higher degree of perfection than the present specimen. Growth features produced contrasts in the topographs of all the flux grown crystals. Some of these crystals had a fairly low dislocation density and dislocations could be resolved conveniently. Fig.1 shows a typical projection topograph of one such crystal. Dislocation lines observed parallel to  $\langle 2110 \rangle$  were found to be edge type dislocations by performing the usual topo-